This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

- 1 1. (cancelled)
- 1 2. (currently amended): A magnetic head having a magnetoresistive sensor,
- 2 comprising:
- 3 <u>a plurality of sensor layers;</u>
- a hard bias/lead structure being disposed at side areas of said sensor layers, said
- 5 hard bias/lead structure including:
- 6 a hard bias layer having a crystalline structure and electrical lead layer having an ordered
- 7 crystalline structure, and wherein said crystalline structure of said lead is epitaxially
- 8 matched to said crystalline structure of said hard bias layer, and A magnetic head as
- 9 described in claim 1, wherein said hard bias layer is composed of a cobalt alloy, and
- wherein said lead layer is formed with a B2 structure.
- 1 3. (original): A magnetic head as described in claim 2 wherein said lead layer is
- 2 composed of NiAl.
- 1 4. (original): A magnetic head as described in claim 2 wherein said lead layer is
- 2 comprised of NiAl, wherein the Ni composition ranges from approximately 45% to
- 3 approximately 60%.

3

- 1 5. (original): A magnetic head as described in claim 4 wherein said Ni composition
- 2 is approximately 50%.
- 1 6. (cancelled)
- 1 7. (currently amended): A magnetic head as described in claim 6 A magnetic head
- 2 <u>having a magnetoresistive sensor, comprising:</u>
- 3 <u>a plurality of sensor layers;</u>
- a hard bias/lead structure being disposed at side areas of said sensor layers, said
- 5 hard bias/lead structure including an electrical lead layer having an ordered crystalline
- 6 structure; and wherein said electrical lead layer ordered crystalline structure is selected
- 7 from the group consisting of B2, L1₀, L1₁, Ll₂ and D0₃.
- 1 8. (currently amended): A magnetic head as described in claim 6 A magnetic head
- 2 <u>having a magnetoresistive sensor, comprising:</u>
- 3 <u>a plurality of sensor layers;</u>
- a hard bias/lead structure being disposed at side areas of said sensor layers, said
- 5 hard bias/lead structure including an electrical lead layer having an ordered crystalline
- 6 structure; and wherein said electrical lead layer is comprised of a material selected from
- 7 the group consisting of NiAl, CuAu, Cu₃Au, Ni₃Al and Fe₃Al.
- 1 9. (original): A magnetic head having a magnetoresistive sensor, comprising:

- 2 a plurality of sensor layers;
- a hard bias/lead structure being disposed at side areas of said sensor layers, said
- 4 hard bias/lead structure including a hard bias layer that is comprised of a cobalt alloy, and
- 5 an electrical lead layer that is comprised of an NiAl alloy and is deposited directly upon
- 6 said hard bias layer.
- 1 10. (original): A magnetic head as described in claim 9 wherein said NiAl electrical
- 2 lead has a B2 crystalline structure.
- 1 11. (original): A magnetic head as described in claim 9 wherein said NiAl lead layer
- 2 includes Ni having a composition between 45% Ni and 60% Ni.
- 1 12. (original): A magnetic head as described in claim 11 wherein said Ni
- 2 composition is approximately 50%.
- 1 13. (cancelled)
- 1 14. (currently amended): A hard disk drive as described in claim 13, A hard disk
- 2 <u>drive including a magnetic head having a magnetoresistive sensor, comprising:</u>
- 3 <u>a plurality of sensor layers;</u>
- 4 <u>a hard bias/lead structure being disposed at side areas of said sensor layers, said</u>
- 5 <u>hard bias/lead structure including:</u>

- 6 a hard bias layer having a crystalline structure and electrical lead layer having an ordered
- 7 <u>crystalline structure</u>, and wherein said crystalline structure of said lead is epitaxially
- 8 matched to said crystalline structure of said hard bias layer; and wherein said hard bias
- 9 layer is composed of a cobalt alloy, and wherein said lead layer is formed with a B2
- 10 structure.
- 1 15. (original): A hard disk drive as described in claim 14 wherein said lead layer is
- 2 composed of NiAl.
- 1 16. (original): A hard disk drive as described in claim 14 wherein said lead layer is
- 2 comprised of NiAl, wherein the Ni composition ranges from approximately 45% to
- 3 approximately 60%.
- 1 17. (original): A hard disk drive as described in claim 16 wherein said Ni
- 2 composition is approximately 50%.
- 1 18. (cancelled)
- 1 19. A-hard disk-drive including a magnetic head as described in claim-18 A hard disk
- 2 <u>drive including a magnetic head having a magnetoresistive sensor, comprising:</u>
- 3 <u>a plurality of sensor layers;</u>

- 4 <u>a hard bias/lead structure being disposed at side areas of said sensor layers, said</u>
- 5 <u>hard bias/lead structure including an electrical lead layer having an ordered crystalline</u>
- 6 structure; and wherein said ordered crystalline structure is selected from the group
- 7 consisting of B2, L1₀, L1₁, Ll₂ and D0₃.
- 1 20. (currently amended): A hard disk drive including a magnetic head as described in
- 2 elaim 18 A hard disk drive including a magnetic head having a magnetoresistive sensor,
- 3 <u>comprising:</u>
- 4 <u>a plurality of sensor layers;</u>
- 5 <u>a hard bias/lead structure being disposed at side areas of said sensor layers, said</u>
- 6 hard bias/lead structure including an electrical lead layer having an ordered crystalline
- 7 structure; and wherein said electrical lead is comprised of a material selected from the
- 8 group consisting of NiAl, CuAu, Cu₃Au, Ni₃Al and Fe₃Al.
- 1 21. (original): A hard disk drive including a magnetic head having a magnetoresistive
- 2 sensor, comprising:
- 3 a plurality of sensor layers;
- 4 a hard bias/lead structure being disposed at side areas of said sensor layers, said
- 5 hard bias/lead structure including a hard bias layer that is comprised of a cobalt alloy, and
- 6 an electrical lead layer that is comprised of an NiAl alloy and is deposited directly upon
- 7 said hard bias layer.

- 1 22. (original): A hard disk drive as described in claim 21 wherein said NiAl electrical
- 2 lead has a B2 crystalline structure.
- 1 23. (original): A hard disk drive as described in claim 21 wherein said NiAl lead
- 2 layer includes Ni having a composition between 45% Ni and 60% Ni.
- 1 24. (original): A hard disk drive as described in claim 23 wherein said Ni
- 2 composition is approximately 50%.
- 1 25. (withdrawn): A method for fabricating a magnetic head, comprising:
- 2 fabricating a plurality of sensor layers upon a substrate, said sensor layers being
- 3 formed with end portions thereof;
- 4 fabricating a hard bias/lead structure proximate said end portions of said sensor
- 5 layers, including:
- 6 fabricating a hard bias layer;
- fabricating an electrical lead layer directly upon said hard bias layer, where said
- 8 electrical lead layer is epitaxially matched to said hard bias layer.
- 1 26. (withdrawn): A method for fabricating a magnetic head as described in claim 25,
- 2 wherein said electrical lead layer is fabricated by ion beam deposition.

- 1 27. (withdrawn): A method for fabricating a magnetic head as described in claim 25,
- 2 wherein said hard bias layer is composed of a cobalt alloy, and wherein said electrical
- 3 lead layer is formed with a B2 structure.
- 1 28. (withdrawn): A method for fabricating a magnetic head as described in claim 25
- 2 wherein said electrical lead layer is composed of NiAl.
- 1 29. (withdrawn): A method for fabricating a magnetic head as described in claim 28,
- 2 wherein said electrical lead layer is fabricated by ion beam deposition utilizing a target
- having an Ni_XAI_{1-X} composition where x is between 0.46 and 0.50.
- 1 30. (withdrawn): A method for fabricating a magnetic head, comprising:
- 2 fabricating a plurality of sensor layers upon a substrate, said sensor layer being
- 3 formed with end portions thereof;
- 4 fabricating a hard bias/lead structure proximate end portions of said sensor layers,
- 5 including:
- 6 fabricating a hard bias layer;
- fabricating an electrical lead layer above said hard bias layer, where said lead
- 8 layer is fabricated to have an ordered crystalline structure.

- 1 31. (withdrawn): A method for fabricating a magnetic head as described in claim 30
- 2 wherein said electrical lead layer ordered crystalline structure is selected from the group
- 3 consisting of B2, L1₀, L1₁, Ll₂ and D0₃.
- 1 32. (withdrawn): A method for fabricating a magnetic head as described in claim 30
- 2 wherein said electrical lead layer is comprised of a material selected from the group
- 3 consisting of NiAl, CuAu, Cu₃Au, Ni₃Al and Fe₃Al.
- 1 33. (withdrawn): A method for fabricating a magnetic head as described in claim 32,
- 2 wherein said electrical lead layer is fabricated by ion beam deposition.